

**IS3051 / IS3052****ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise specified)**INPUT**

Parameter	Symbol	Test Condition	Min	Typ.	Max	Unit
Forward Voltage	$V_F$	$I_F = 20\text{mA}$		1.2	1.5	V
Reverse Current	$I_R$	$V_R = 6\text{V}$		0.05	10	$\mu\text{A}$

**OUTPUT**

Parameter	Symbol	Test Condition	Min	Typ.	Max	Unit
Peak Off-state Current Either Direction	$I_{\text{DRM}}$	$V_{\text{DRM}} = 600\text{V}$ $I_F = 0\text{mA}$ Note 1			100	nA
On-State Voltage Either Direction	$V_{\text{TM}}$	$I_{\text{TM}} = 100\text{mA (peak)}$			3.0	V
Critical Rate of Rise of Off-State Voltage	dv/dt	$I_F = 0\text{mA}$	1000			V/ $\mu\text{s}$

**COUPLED**

Parameter	Symbol	Test Condition	Min	Typ.	Max	Unit
Input Trigger Current Either Direction	$I_{\text{FT}}$	$V_{\text{TM}} = 3\text{V}$ Note 2 IS3051 IS3052			15 10	mA
Holding Current Either Direction	$I_H$			200		$\mu\text{A}$

**ISOLATION**

Parameter	Symbol	Test Condition	Min	Typ.	Max	Unit
Insulation Voltage	$V_{\text{ISO}}$	AC 1 minute, RH 40 to 60% Note 3	5000			$V_{\text{RMS}}$

Note 1 : Test Voltage must be applied within static dv/dt rating.

Note 2 : Guaranteed to trigger at an  $I_F$  value less than or equal to max  $I_{\text{FT}}$ ,  
recommended  $I_F$  lies between Rated  $I_{\text{FT}}$  to Absolute Max  $I_F$ .

Note 3 : Measured with input leads shorted together and output leads shorted together.

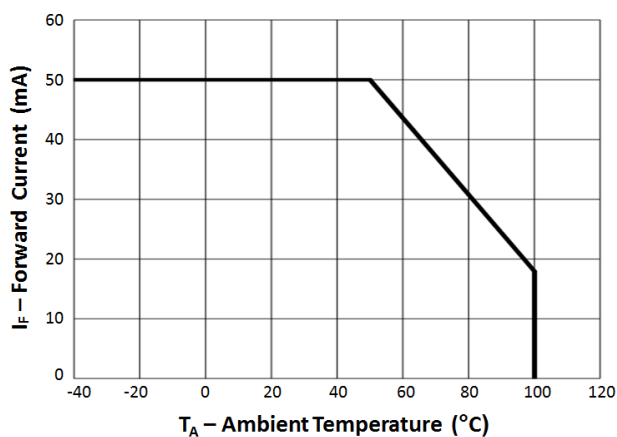


Fig 1 Forward Current vs Ambient Temperature

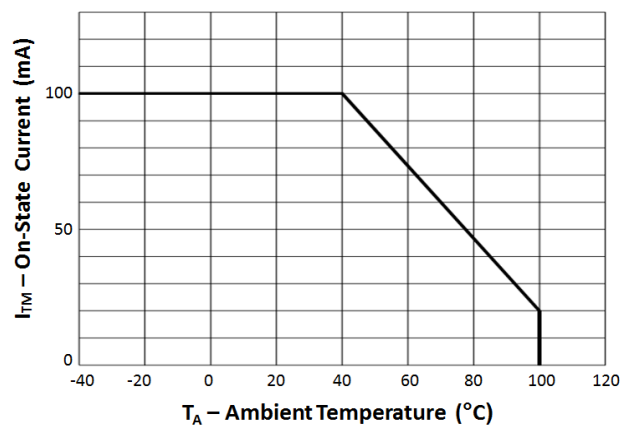


Fig 2 On-State Current vs Ambient Temperature

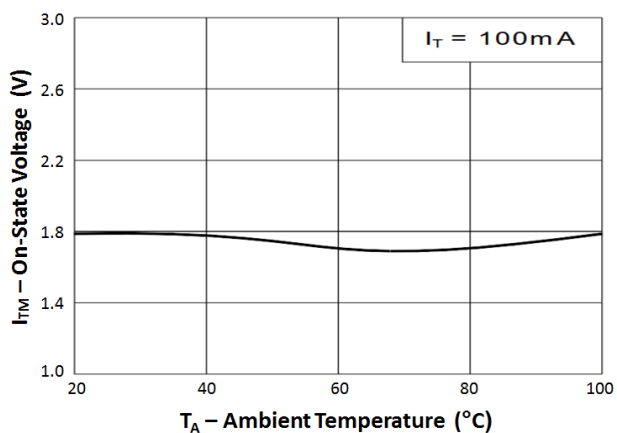


Fig 3 On-State Voltage vs Ambient Temperature

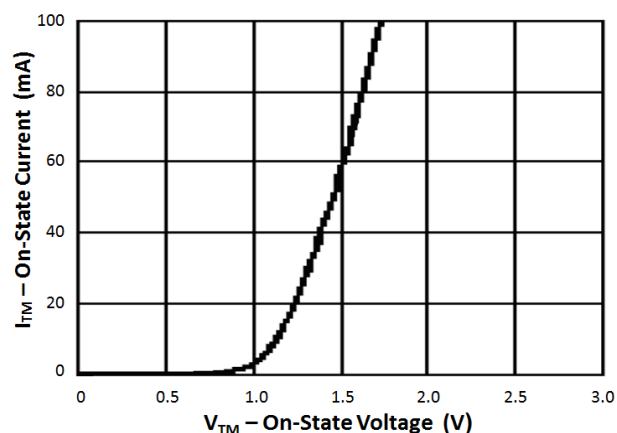


Fig 4 On-State Current vs On-State Voltage

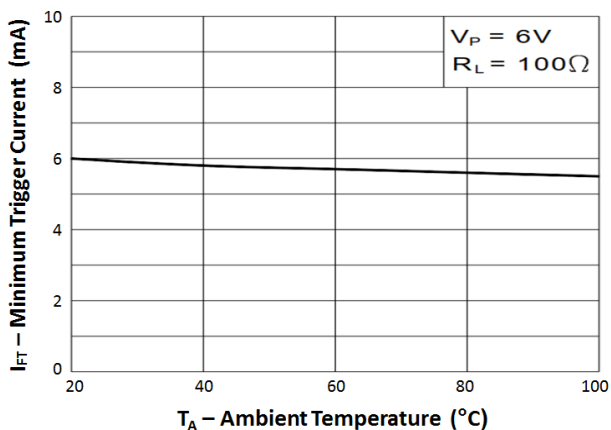


Fig 5 Minimum Trigger Current vs Ambient Temperature

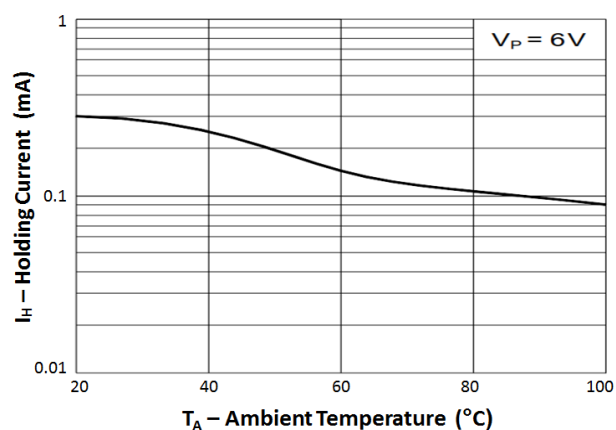


Fig 6 Holding Current vs Ambient Temperature

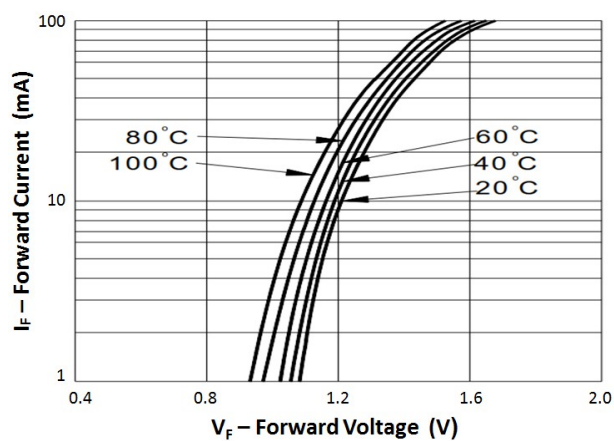


Fig 7 Forward Current vs Forward Voltage

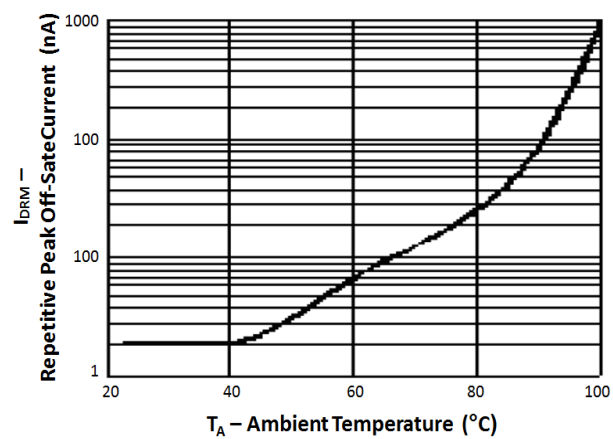


Fig 8 Repetitive Peak Off-State Current vs Ambient Temperature



## IS3051 / IS3052

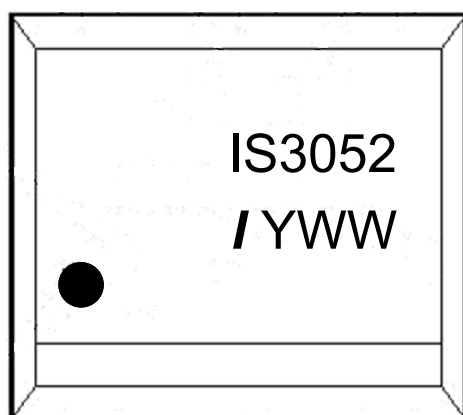
### ORDER INFORMATION

IS3051 / IS3052 (UL Approval)			
After PN	PN	Description	Packing quantity
None	IS3051, IS3052	Standard DIP6	65 pcs per tube
G	IS3051G, IS3052G	10mm Lead Spacing	65 pcs per tube
SM	IS3051SM, IS3052SM	Surface Mount	65 pcs per tube
SMT&R	IS3051SMT&R, IS3052SMT&R	Surface Mount Tape & Reel	1000 pcs per reel

IS3051X / IS3052X (UL Approval and VDE Approvals)			
After PN	PN	Description	Packing quantity
None	IS3051X, IS3052X	Standard DIP6	65 pcs per tube
G	IS3051XG, IS3052XG	10mm Lead Spacing	65 pcs per tube
SM	IS3051XSM, IS3052XSM	Surface Mount	65 pcs per tube
SMT&R	IS3051XSMT&R, IS3052XSMT&R	Surface Mount Tape & Reel	1000 pcs per reel

### DEVICE MARKING

Example : IS3052



IS3052      denotes Device Part Number  
/            denotes Isocom  
Y            denotes 1 digit Year code  
WW        denotes 2 digit Week code

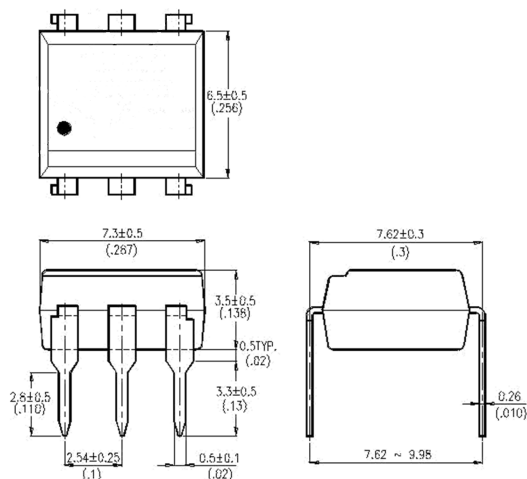


**ISOCOM**  
COMPONENTS

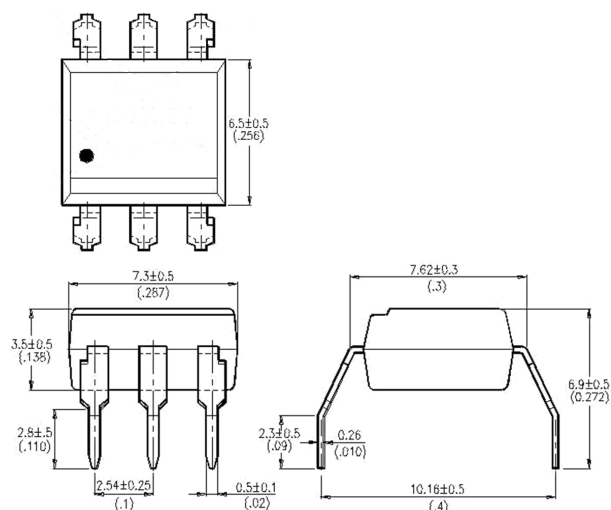
## IS3051 / IS3052

### PACKAGE DIMENSIONS in mm (inch)

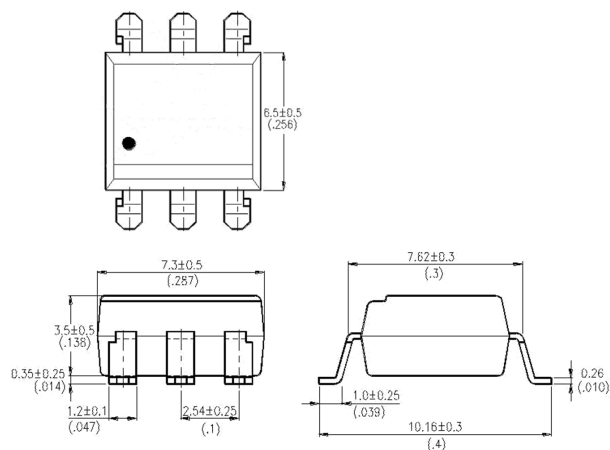
#### DIP



#### G Form

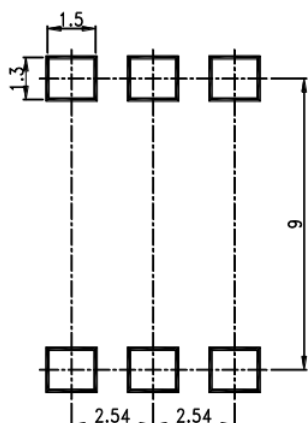


#### SMD

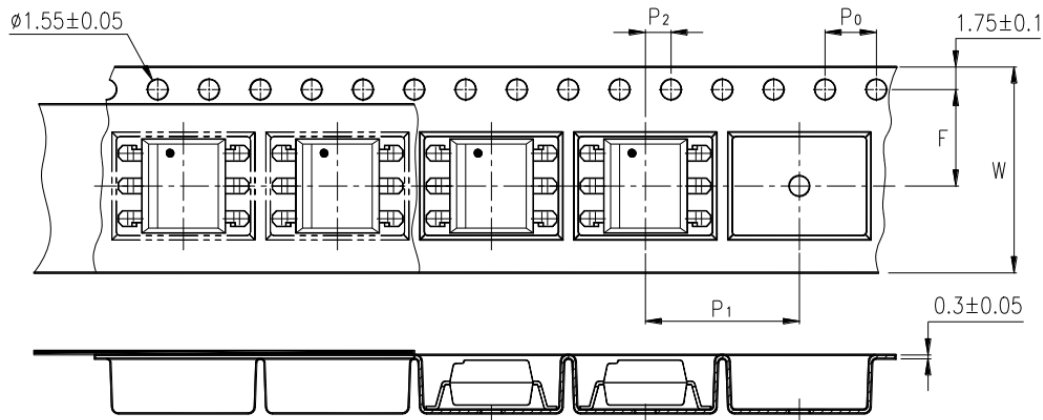




**RECOMMENDED PAD LAYOUT FOR SMD (mm)**



**TAPE AND REEL PACKAGING**



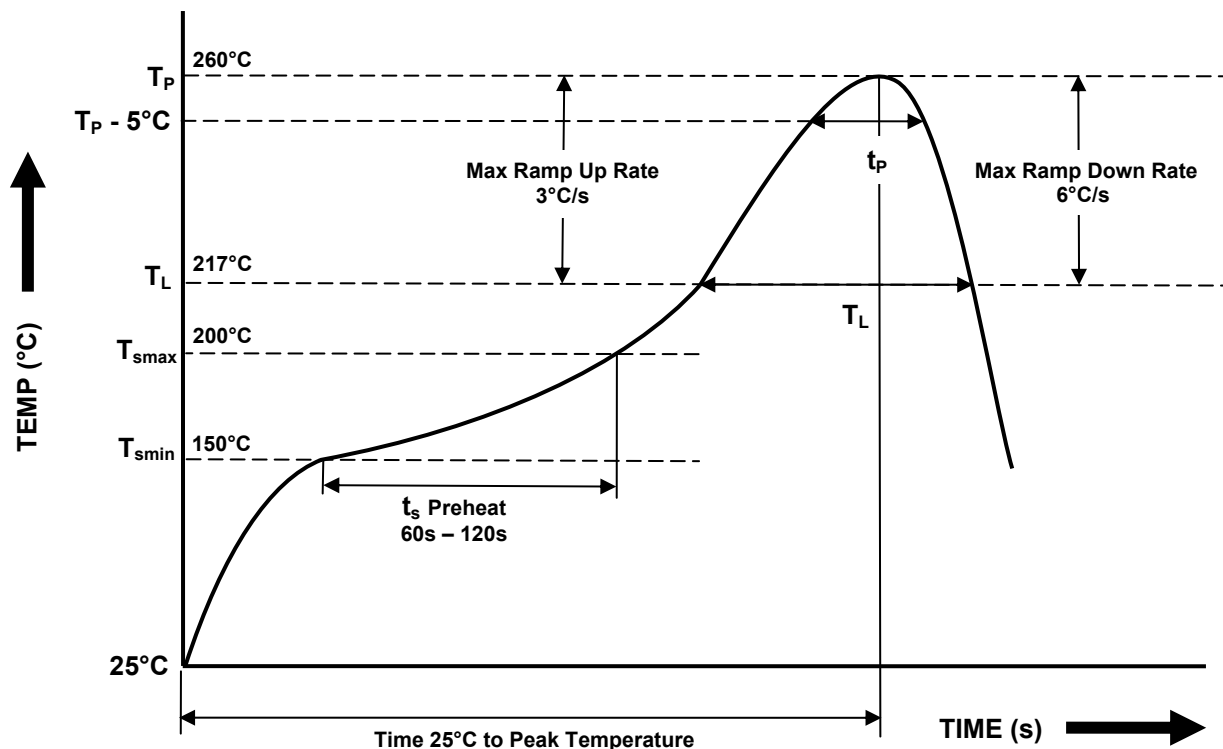
Description	Symbol	Dimension mm (inch)
Tape Width	W	$16 \pm 0.3$ (0.63)
Pitch of Sprocket Holes	$P_0$	$4 \pm 0.1$ (0.15)
Distance of Compartment to Sprocket Holes	F	$7.5 \pm 0.1$ (0.295)
	$P_2$	$2 \pm 0.1$ (0.079)
Distance of Compartment to Compartment	$P_1$	$12 \pm 0.1$ (0.472)



### IR REFLOW SOLDERING TEMPERATURE PROFILE

Note : One Time Reflow Soldering is Recommended.

Do Not Immerse Device Body in Solder Paste.



Profile Details	Conditions
<b>Preheat</b> <ul style="list-style-type: none"><li>- Min Temperature (<math>T_{SMIN}</math>)</li><li>- Max Temperature (<math>T_{SMAX}</math>)</li><li>- Time <math>T_{SMIN}</math> to <math>T_{SMAX}</math> (<math>t_s</math>)</li></ul>	150°C 200°C 60s - 120s
<b>Soldering Zone</b> <ul style="list-style-type: none"><li>- Peak Temperature (<math>T_P</math>)</li><li>- Time at Peak Temperature</li><li>- Liquidous Temperature (<math>T_L</math>)</li><li>- Time within 5°C of Actual Peak Temperature (<math>T_P - 5^\circ\text{C}</math>)</li><li>- Time maintained above <math>T_L</math> (<math>t_L</math>)</li><li>- Ramp Up Rate (<math>T_L</math> to <math>T_P</math>)</li><li>- Ramp Down Rate (<math>T_P</math> to <math>T_L</math>)</li></ul>	260°C 10s max 217°C 30s max 60s - 100s 3°C/s max 6°C/s max
Average Ramp Up Rate ( $T_{smax}$ to $T_P$ )	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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